

INFORMATION DISCLOSURE CITATION IN AN APPLICATION		PATENT DOCKET NO. 1248-0579P	APPLICATION NO. 10/084184			
(Use several sheets if necessary)		APPLICANT MIYAMOTO, Masayuki	FILING DATE February 28, 2002			
U.S. PATENT DOCUMENTS		GROUP 2817	SUB CLASS —			
EXAMINER'S INITIALS	DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	FILING DATE IF APPROPRIATE
H. c.	6,100,761	2000-06-08	Ezell	—	—	—
X						
FOREIGN PATENT DOCUMENTS						
	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUB CLASS	TRANSLATION YES NO
H. c.						
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OTHER DOCUMENTS (Exclude Name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.) date, page(s), volume-issue number(s), publisher, city and/or country where published.)						
H. c.	SOORAPANTH, Theerachet "RF Linearity of Short-Channel MOSFETs" First International Workshop on Design of Mixed-Mode Integrated Circuits and Applications, July 1997, pp. 81-84.					
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EXAMINER	DATE CONSIDERED			4/19/03		
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